

CGHV60040D 40 W, 6.0 GHz, GaN HEMT Die

Cree's CGHV60040D is a gallium nitride (GaN) High Electron Mobility Transistor (HEMT). GaN has superior properties



PN: CGHV60040D

compared to silicon or gallium arsenide, including higher

breakdown voltage, higher saturated electron drift velocity, and higher thermal

conductivity. GaN HEMTs offer greater power density and wider bandwidths compared to Si and GaAs transistors.

FEATURES

- 18 dB Typical Small Signal Gain at 4 GHz
- 17 dB Typical Small Signal Gain at 6 GHz
- 65% Typical Power Added Efficiency
- 40 W Typical P_{SAT}
- 50 V Operation
- High Breakdown Voltage
- Up to 6 GHz Operation

APPLICATIONS

- Cellular Infrastructure
- Class AB, Linear amplifiers suitable for OFDM, W-CDMA, LTE, EDGE, CDMA waveforms



Packaging Information

- Bare die are shipped on tape or in Gel-Pak® containers.
- Non-adhesive tacky membrane immobilizes die during shipment.



Absolute Maximum Ratings (not simultaneous)

Parameter	Symbol	Rating	Units	Conditions	
Drain-source Voltage	V _{DSS}	150	V _{DC}	25°C	
Gate-source Voltage	V _{GS}	-10, +2	V _{DC}	25°C	
Storage Temperature	T _{stg}	-65, +150	°C		
Operating Junction Temperature	T,	225	°C		
Maximum Drain Current ¹	I _{MAX}	3.2	А	25°C	
Maximum Forward Gate Current	I _{GMAX}	5.2	mA	25°C	
Thermal Resistance, Junction to Case (packaged) ²	R _{ejc}	5.10	°C/W	85°C, 20.8W Dissipation	
Thermal Resistance, Junction to Case (die only)	R _{ejc}	3.27	°C/W	85°C, 20.8W Dissipation	
Mounting Temperature	Τ _s	320	°C	30 seconds	

Note¹ Current limit for long term reliable operation.

Note² Eutectic die attach using 80/20 AuSn mounted to a 10 mil thick Cu15Mo85 carrier.

Electrical Characteristics (Frequency = 6 GHz unless otherwise stated; $T_c = 25$ °C)

Characteristics	Symbol	Min.	Тур.	Max.	Units	Conditions
DC Characteristics						
Gate Pinch-Off Voltage	V _P	-3.8	-3.0	-2.3	V	$V_{_{\rm DS}}$ = 10 V, $I_{_{\rm D}}$ = 5.2 mA
Drain Current ¹	\mathbf{I}_{DSS}	4.2	5.2	-	А	$V_{\rm DS}$ = 6 V, $V_{\rm GS}$ = 2.0 V
Drain-Source Breakdown Voltage	V _{BD}	150	-	-	V	$V_{gs} = -8 V, I_{d} = 5.2 mA$
On Resistance	R _{on}	-	0.56	-	Ω	$V_{\text{DS}} = 0.1 \text{ V}$
Gate Forward Voltage	V_{G-ON}	-	1.9	-	V	$I_{gs} = 5.2 \text{ mA}$
RF Characteristics						
Small Signal Gain	G _{ss}	-	17	-	dB	$V_{_{DD}}$ = 50 V, $I_{_{DQ}}$ = 65 mA
Saturated Power Output ^{2,3}	P _{SAT}	-	40	-	W	$V_{_{\rm DD}}$ = 50 V, $I_{_{\rm DQ}}$ = 65 mA
Drain Efficiency ⁴	η	-	65	-	%	$V_{_{\rm DD}}$ = 50 V, $I_{_{\rm DQ}}$ = 65 mA, $P_{_{\rm SAT}}$ = 40 W
Intermodulation Distortion	IM3	-	-30	-	dBc	$\label{eq:V_dd} \begin{array}{l} V_{_{DD}} = 50 \mbox{ V, } I_{_{DQ}} = 65 \mbox{ mA,} \\ P_{_{OUT}} = 40 \mbox{ W PEP} \end{array}$
Output Mismatch Stress	VSWR	-	-	10:1	Ψ	No damage at all phase angles, $V_{_{DD}}$ = 50 V, $I_{_{DQ}}$ = 65 mA $P_{_{OUT}}$ = 40 W CW
Dynamic Characteristics						
Input Capacitance	C _{GS}	-	7.1	-	pF	$V_{_{\rm DS}}$ = 50 V, $V_{_{\rm gs}}$ = -8 V, f = 1 MHz
Output Capacitance	C _{DS}	-	1.6	-	pF	$V_{_{\rm DS}}$ = 50 V, $V_{_{\rm gs}}$ = -8 V, f = 1 MHz
Feedback Capacitance	C _{GD}	-	0.15	-	pF	$V_{_{\rm DS}}$ = 50 V, $V_{_{\rm gs}}$ = -8 V, f = 1 MHz

Notes:

¹ Scaled from PCM data

 2 P_{SAT} is defined as I_G = 0.52 mA.

³ Pulsed 100 µsec, 10%

⁴ Drain Efficiency = P_{OUT} / P_{DC}

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DIE Dimensions (units in microns)





Assembly Notes:

- Recommended solder is AuSn (80/20) solder. Refer to Cree's website for the Eutectic Die Bond Procedure application note at www.cree.com/wireless.
- Vacuum collet is the preferred method of pick-up.
- The backside of the die is the Source (ground) contact.
- Die back side gold plating is 5 microns thick minimum.
- Thermosonic ball or wedge bonding are the preferred connection methods.
- Gold wire must be used for connections.
- Use the die label (XX-YY) for correct orientation, see arrow 9 in the drawing above.

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Typical Performance

Figure 1. - CGHV60040D Output Power, Gain and Efficiency vs. Input Power at Tcase = 25° C V_{DD} = 50 V, I_{DO} = 65 mA, Frequency = 2.7 GHz



Figure 2. - CGHV60040D $G_{_{MAX}}$ and K Factor vs. Frequency at Tcase = 25°C $V_{_{DD}}$ = 50 V, $I_{_{DQ}}$ = 65 mA



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Typical Die S-Parameters (Small Signal, $V_{_{DS}}$ = 50 V, $I_{_{DQ}}$ = 65 mA, magnitude / angle)

Frequency	Mag S11	Ang S11	Mag S21	Ang S21	Mag S12	Ang S12	Mag S22	Ang S22
0.500	0.935	-124.81	17.697	105.17	0.018	16.26	0.468	-61.04
0.600	0.932	-132.78	15.111	99.07	0.019	10.39	0.461	-66.42
0.700	0.930	-138.77	13.108	93.98	0.019	5.52	0.462	-71.19
0.800	0.929	-143.42	11.520	89.59	0.019	1.35	0.468	-75.54
0.900	0.929	-147.12	10.235	85.69	0.019	-2.32	0.478	-79.56
1.000	0.929	-150.12	9.175	82.18	0.019	-5.62	0.491	-83.30
1.100	0.930	-152.61	8.287	78.96	0.018	-8.62	0.506	-86.79
1.200	0.931	-154.70	7.532	75.98	0.018	-11.38	0.521	-90.07
1.300	0.932	-156.49	6.884	73.19	0.018	-13.94	0.537	-93.16
1.400	0.933	-158.04	6.320	70.57	0.018	-16.34	0.553	-96.07
1.500	0.934	-159.39	5.827	68.10	0.018	-18.59	0.570	-98.82
1.600	0.936	-160.58	5.391	65.75	0.017	-20.72	0.586	-101.42
1.700	0.937	-161.64	5.003	63.51	0.017	-22.73	0.602	-103.88
1.800	0.939	-162.59	4.657	61.38	0.017	-24.64	0.617	-106.22
1.900	0.940	-163.45	4.346	59.35	0.016	-26.45	0.633	-108.45
2.000	0.941	-164.24	4.065	57.40	0.016	-28.18	0.647	-110.56
2.100	0.943	-164.95	3.810	55.53	0.016	-29.82	0.661	-112.57
2.200	0.944	-165.61	3.579	53.73	0.016	-31.39	0.675	-114.49
2.300	0.946	-166.22	3.367	52.01	0.015	-32.89	0.688	-116.32
2.400	0.947	-166.79	3.174	50.35	0.015	-34.32	0.701	-118.07
2.500	0.948	-167.32	2.996	48.75	0.015	-35.70	0.713	-119.74
2.600	0.950	-167.82	2.833	47.21	0.014	-37.01	0.724	-121.34
2.700	0.951	-168.29	2.682	45.73	0.014	-38.26	0.735	-122.87
2.800	0.952	-168.73	2.542	44.29	0.014	-39.47	0.745	-124.33
2.900	0.953	-169.14	2.413	42.91	0.014	-40.62	0.755	-125.74
3.000	0.954	-169.54	2.294	41.57	0.013	-41.73	0.765	-127.08
3.200	0.957	-170.27	2.079	39.03	0.013	-43.81	0.782	-129.62
3.400	0.959	-170.94	1.892	36.65	0.012	-45.72	0.798	-131.95
3.600	0.960	-171.55	1.729	34.42	0.012	-47.49	0.812	-134.12
3.800	0.962	-172.11	1.585	32.31	0.011	-49.12	0.825	-136.13
4.000	0.964	-172.64	1.458	30.33	0.011	-50.63	0.837	-137.99
4.200	0.965	-173.13	1.346	28.45	0.010	-52.03	0.848	-139.73
4.400	0.966	-173.59	1.246	26.67	0.010	-53.32	0.857	-141.35
4.600	0.967	-174.02	1.156	24.99	0.009	-54.51	0.866	-142.87
4.800	0.969	-174.43	1.076	23.38	0.009	-55.62	0.874	-144.29
5.000	0.970	-174.82	1.004	21.85	0.009	-56.64	0.882	-145.63
5.200	0.970	-175.19	0.939	20.39	0.008	-57.59	0.888	-146.88
5.400	0.971	-175.54	0.880	19.00	0.008	-58.46	0.894	-148.07
5.600	0.972	-175.88	0.826	17.66	0.008	-59.27	0.900	-149.18
5.800	0.973	-176.20	0.777	16.37	0.007	-60.01	0.905	-150.24
6.000	0.973	-176.51	0.732	15.14	0.007	-60.69	0.910	-151.24

To download the s-parameters in s2p format, go to the CGHV60040D Product Page and click the documentation tab.

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Part Number System



Value	Units
6.0	GHz
40	W
Bare Die	-
	6.0 40

Table 1.

Note¹: Alpha characters used in frequency code indicate a value greater than 9.9 GHz. See Table 2 for value.

Character Code	Code Value
А	0
В	1
С	2
D	3
Е	4
F	5
G	6
н	7
J	8
К	9
Examples:	1A = 10.0 GHz 2H = 27.0 GHz

Table 2.

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